SP4322 Series 0.4pF 11A Bidirectional Diode Array







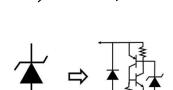


Note: This package image is for example and reference only. for detail package drawing, please refer to the package section in this datasheet.

Pinout



Functional Block Diagram



Description

SP4322 is specifically designed to protect high-speed interfaces against ElectroStatic Discharge (ESD), such as DisplayPort interfaces and USB 3.1 Gen 1. The signal line is protected by low line capacitance of 0.4 pF typical.

SP4322 can absorb repetitive ESD strikes above the maximum level specified in the IEC 61000-4-2 international standard without performance degradation and safely dissipate 11A of $8/20\mu s$ surge current (IEC 61000-4-5 2nd edition).

Excellent low capacitance, clamping capability, low leakage, and fast response time make this part an ideal solution for protecting high speed data lines.

Features & Benefits

- ESD, IEC 61000-4-2, ±18kV contact, ±30kV air
- EFT, IEC 61000-4-4, 40A (5/50ns)
- Lightning, 11A (8/20µs as defined in IEC 61000-4-5 2nd edition)
- Low capacitance of 0.4pF (TYP @ VR=0V)
- Low leakage current of 1nA (TYP) at 5V
- Halogen free, lead free and RoHS compliant
- Moisture Sensitivity Level (MSL -1)
- AEC-Q101 Qualified

Applications

- USB 3.1
- DisplayPort
- S-ATA

- NFC
- 1G/2.5G/10G Ethernet

Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.



Absolute Maximum Ratings

Symbol	Parameter	Value	Units
I _{PP}	Peak Current (t _p =8/20µs)	11	А
T _{op}	Operating Temperature	-40 to 125	°C
T _{STOR}	Storage Temperature	-55 to 150	°C

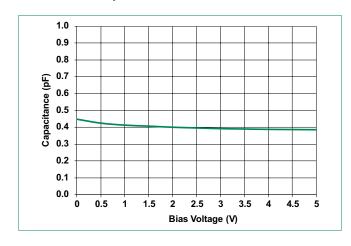
Caution: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the component at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Electrical Characteristics (T_{OP}=25°C)

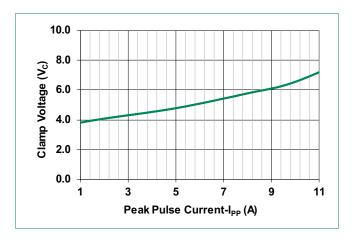
Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Reverse Standoff Voltage	V _{RWM}	$I_R = 1 \mu A$			5	V
Breakdown Voltage	$V_{\mathtt{BR}}$	I _R =1mA		9		V
Reverse Leakage Current	I _{LEAK}	V _R =5V		1	100	nA
Holding Voltage	V_{HOLD}	I/O to I/O		2.3		V
	\/	$I_{pp}=1A, t_{p}=8/20 \mu s$		4		V
Clamp Voltage ¹	V _C	$I_{pp} = 11A, t_p = 8/20 \mu s$		8		V
Dynamic Resistance ²	R _{DYN}	TLP, t _p =100ns		0.2		Ω
ESD Withstand Voltage ¹ V _{ESI}	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	IEC 61000-4-2 (Contact Discharge)	±18			kV
	V _{ESD}	IEC 61000-4-2 (Air Discharge)	±30			kV
Diode Capacitance ¹	C _{IO-GND}	Reverse Bias=0V, f=1MHz		0.4	0.5	pF

Note:

Capacitance vs. Reverse Bias



Clamping voltage vs. IPP for 8/20µs waveshape



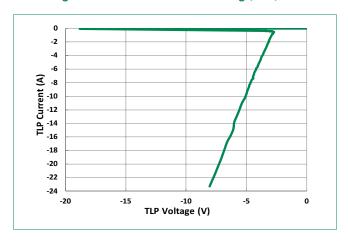


^{1.} Parameter is guaranteed by design and/or component characterization.

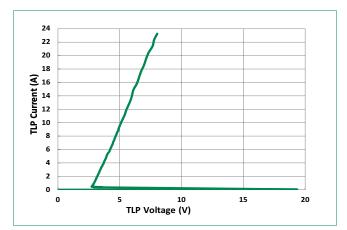
^{2.}Transmission Line Pulse (TLP) with 100ns width, 0.2ns rise time, and average window t1=70ns to t2= 90ns

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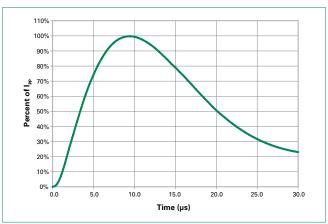
Negative Transmission Line Pulsing (TLP) Plot



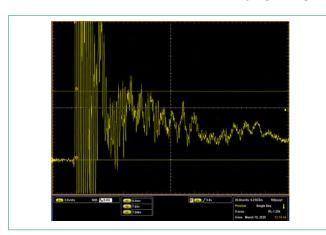
Positive Transmission Line Pulsing (TLP) Plot



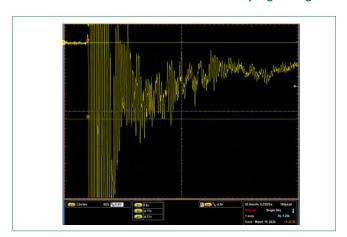
8/20µs Pulse Waveform







IEC 61000-4-2 -8 kV Contact ESD Clamping Voltage





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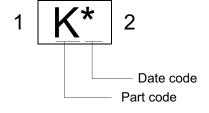
Soldering Parameters

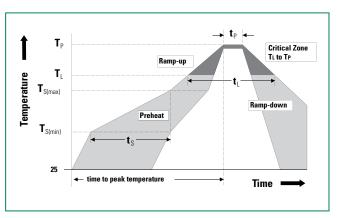
Reflow Cond	Pb – Free assembly		
Pre Heat	-Temperature Min (T _{s(min)})	150°C	
	-Temperature Max (T _{s(max)})	200°C	
	-Time (min to max) (t _s)	60 - 120 secs	
Average ram	Average ramp up rate (Liquidus) Temp (T _L) to peak		
$T_{S(max)}$ to T_L -	T _{S(max)} to T _L - Ramp-up Rate		
Reflow	-Temperature (T _L) (Liquidus)	217°C	
	-Temperature (t _L)	60 - 150 seconds	
Peak Temper	260+0/-5 °C		
Time within	30 seconds		
Ramp-down Rate		6°C/second max	
Time 25°C to peak Temperature (T _p)		8 minutes Max.	
Do not exce	260°C		

Ordering Information

Part Number	Package	Min. Order Qty.
SP4322-01ETG	SOD882	10,000

Part Marking System

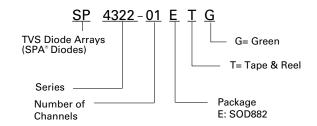




Product Characteristics

Lead Plating	Pre-Plated Frame, Tin
Lead material	Copper Alloy
Substrate Material	Silicon
Body Material	Molded Compound
Flammability	UL Recognized compound meeting flammability rating V-0

Part Numbering System

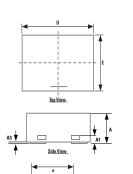


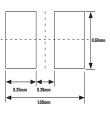


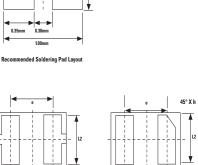
SP4322 Series

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Package Dimensions — SOD882

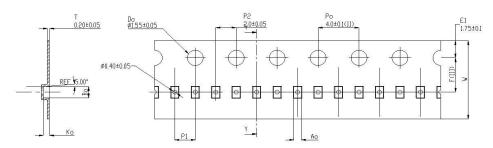






Symbol	DIMENSIONS (mm)			
	Min.	Nor.	Max.	
Α	0.36	0.45	0.55	
A1	0.125/0.150 (REF)			
А3	0.00	0.02	0.05	
L1	0.20	0.25	0.30	
L2	0.45	0.50	0.55	
D	0.93	1.00	1.07	
E	0.53	0.60	0.67	
е	0.65 BSC			
h	0.07	0.12	0.17	

Embossed Carrier Tape & Reel Specification — SOD882



Symbol	Millimeters
A0	0.70+/-0.045
В0	1.10+/-0.045
K0	0.65+/-0.045
F	3.50+/-0.05
P1	2.00+/-0.10
W	8.00 + 0.30 -0.10

